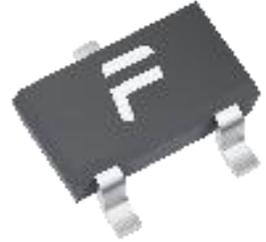
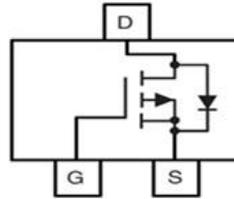


**SOT-23-3L -40V P Channel Enhancement 沟道增强型
MOS Field Effect Transistor 场效应管**



■ **Absolute Maximum Ratings 最大额定值**

| Characteristic 特性参数 | Symbol 符号 | Rat 额定值 | Unit 单位 |
|----------------------------------------|--------------------------------|----------|--------------|
| Drain-Source Voltage 漏极-源极电压 | BV_{DSS} | -40 | V |
| Gate- Source Voltage 栅极-源极电压 | V_{GS} | ± 20 | V |
| Drain Current (continuous)漏极电流-连续 | I_D (at $T_A = 25^\circ C$) | -6 | A |
| Drain Current (pulsed)漏极电流-脉冲 | I_{DM} | -24 | A |
| Total Device Dissipation 总耗散功率 | P_D (at $T_A = 25^\circ C$) | 1500 | mW |
| Thermal Resistance Junction-Ambient 热阻 | $R_{\theta JA}$ | 83 | $^\circ C/W$ |
| Junction/Storage Temperature 结温/储存温度 | T_J, T_{stg} | -55~150 | $^\circ C$ |

■ **Device Marking 产品字标**

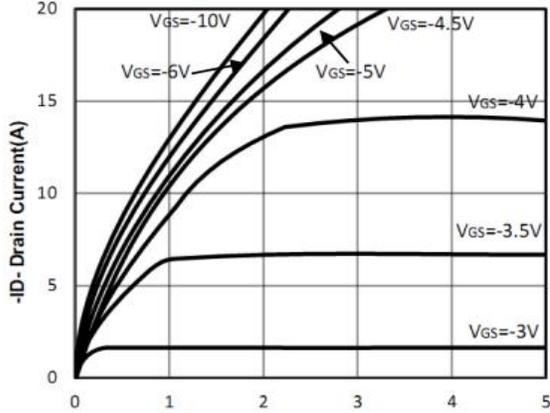
FS6P04=6P04

Electrical Characteristics 电特性

 (T_A=25°C unless otherwise noted 如无特殊说明, 温度为 25°C)

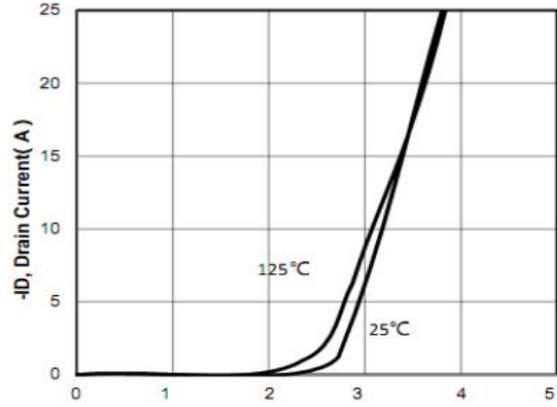
| Characteristic 特性参数 | Symbol 符号 | Min 最小值 | Typ 典型值 | Max 最大值 | Unit 单位 |
|------------------------------------------------------------------------------------------------------------------------------------------------------|---------------------|------------|------------|------------|------------|
| Drain-Source Breakdown Voltage 漏极-源极击穿电压(I _D = -250uA, V _{GS} =0V) | BV _{DSS} | -40 | — | — | V |
| Gate Threshold Voltage 栅极开启电压(I _D = -250uA, V _{GS} = V _{DS}) | V _{GS(th)} | -1 | -1.7 | -2.5 | V |
| Zero Gate Voltage Drain Current 零栅压漏极电流(V _{GS} =0V, V _{DS} = -40V) | I _{DSS} | — | — | -1 | uA |
| Gate Body Leakage 栅极漏电流(V _{GS} =±20V, V _{DS} =0V) | I _{GSS} | — | — | ±100 | nA |
| Static Drain-Source On-State Resistance 静态漏源导通电阻(I _D = -6A, V _{GS} = -10V) (I _D = -5A, V _{GS} = -4.5V) | R _{DS(ON)} | — | 35 45 | 40 58 | mΩ |
| Diode Forward Voltage Drop 内附二极管正向压降(I _{SD} = -2.5A, V _{GS} =0V) | V _{SD} | — | — | -1.2 | V |
| Input Capacitance 输入电容 (V _{GS} =0V, V _{DS} = -20V, f=1MHz) | C _{ISS} | — | 1250 | — | pF |
| Common Source Output Capacitance 共源输出电容(V _{GS} =0V, V _{DS} = -20V, f=1MHz) | C _{OSS} | — | 98 | — | pF |
| Reverse Transfer Capacitance 反馈电容(V _{GS} =0V, V _{DS} = -20V, f=1MHz) | C _{RSS} | — | 80 | — | pF |
| Total Gate Charge 栅极电荷密度 (V _{DS} = -20V, I _D = -5A, V _{GS} = -10V) | Q _g | — | 23 | — | nC |
| Gate Source Charge 栅源电荷密度 (V _{DS} = -20V, I _D = -5A, V _{GS} = -10V) | Q _{gs} | — | 4 | — | nC |
| Gate Drain Charge 栅漏电荷密度 (V _{DS} = -20V, I _D = -5A, V _{GS} = -10V) | Q _{gd} | — | 4 | — | nC |
| Turn-ON Delay Time 开启延迟时间 (V _{DS} = -20V I _D = -5A, R _{GEN} =3 Ω, V _{GS} = -10V) | t _{d(on)} | — | 5 | — | ns |
| Turn-ON Rise Time 开启上升时间 (V _{DS} = -20V I _D = -5A, R _{GEN} =3 Ω, V _{GS} = -10V) | t _r | — | 2 | — | ns |
| Turn-OFF Delay Time 关断延迟时间 (V _{DS} = -20V I _D = -5A, R _{GEN} =3 Ω, V _{GS} = -10V) | t _{d(off)} | — | 51 | — | ns |
| Turn-OFF Fall Time 关断下降时间 (V _{DS} = -20V I _D = -5A, R _{GEN} =3 Ω, V _{GS} = -10V) | t _f | — | 29 | — | ns |

■ Typical Characteristic Curve 典型特性曲线



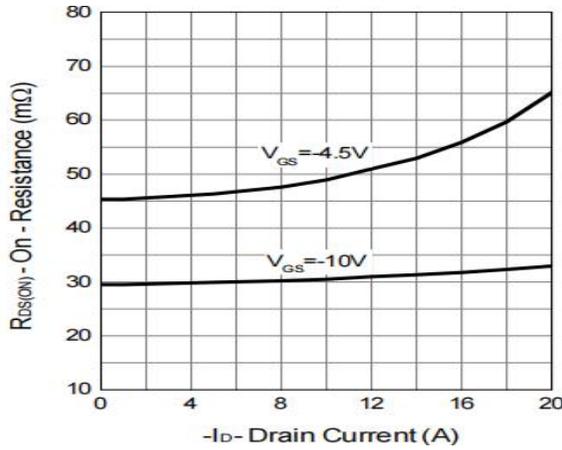
-V_{DS} Drain-Source Voltage (V)

Figure 1: Output Characteristics



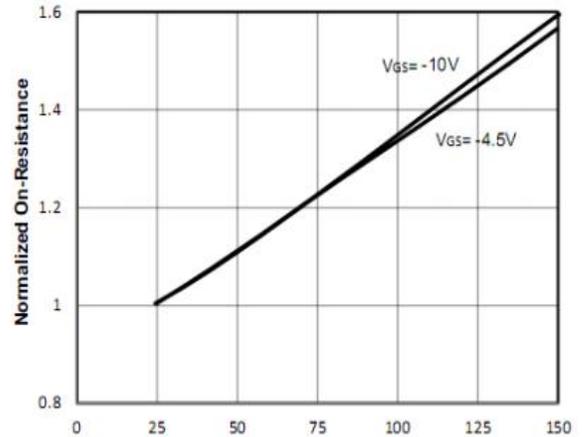
-V_{GS} Gate-Source Voltage (V)

Figure 2: Transfer Characteristics



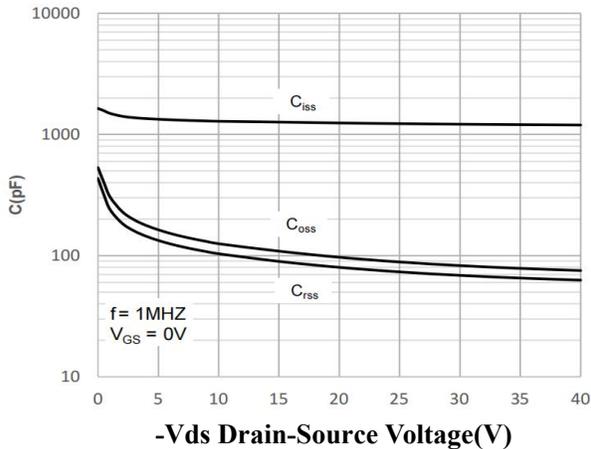
-I_D Drain Current (A)

Figure 3: On-Resistance vs. Drain Current



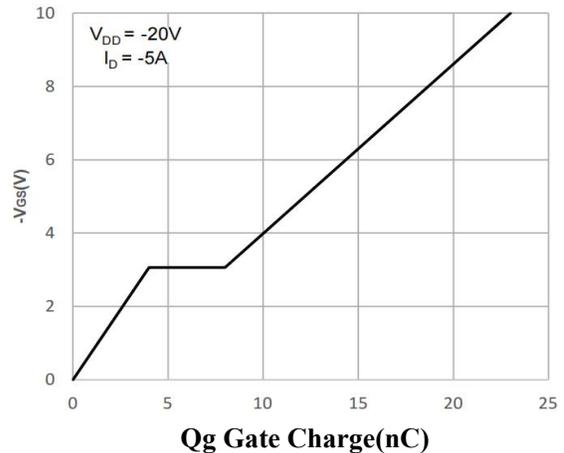
T_J Junction Temperature (°C)

Figure 4: On-Resistance vs. Temperature



-V_{DS} Drain-Source Voltage (V)

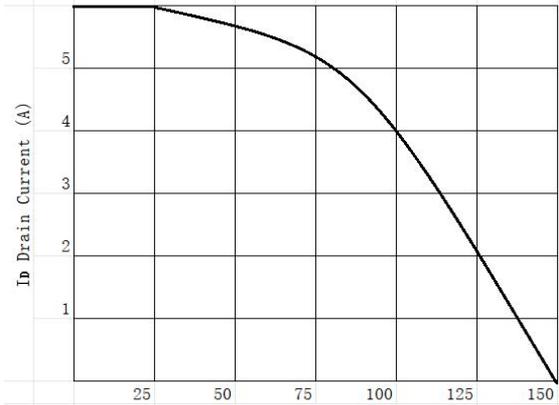
Figure 5: Capacitance Characteristics



Q_g Gate Charge (nC)

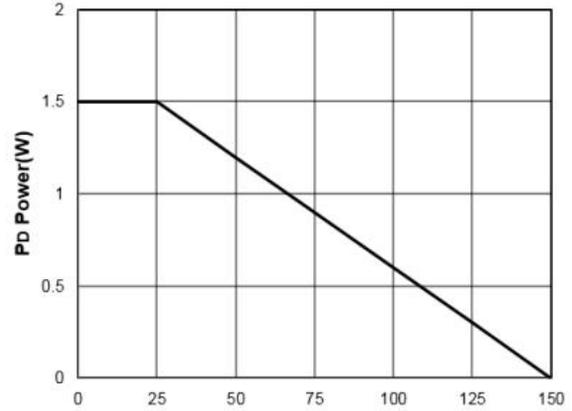
Figure 6: Gate-Charge Characteristics

■ Typical Characteristic Curve 典型特性曲线



T_J Junction Temperature (°C)

Figure 7: Drain Current vs. Temperature



T_J Junction Temperature (°C)

Figure 8: Power Dissipation

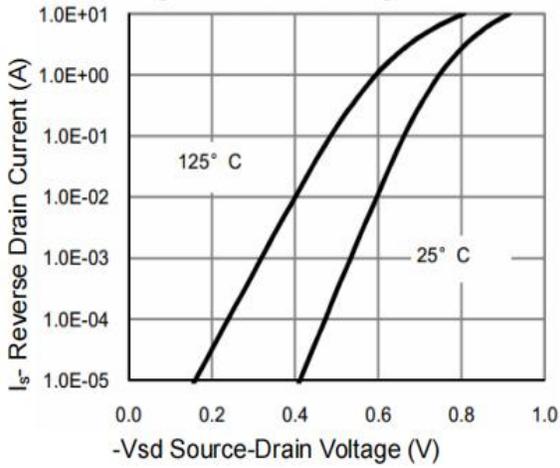


Figure 9: Body Diode Characteristics

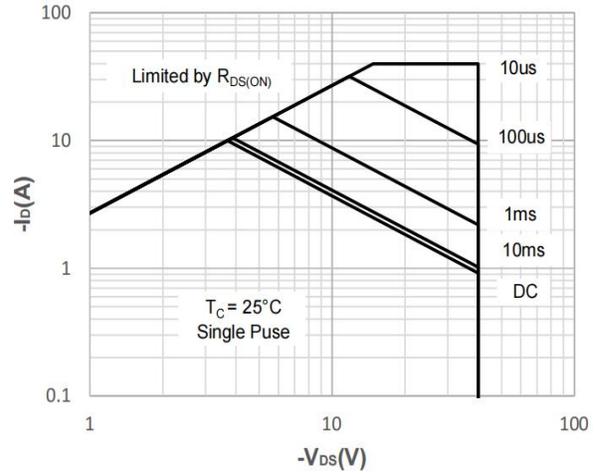


Figure 10: Safe Operating Area

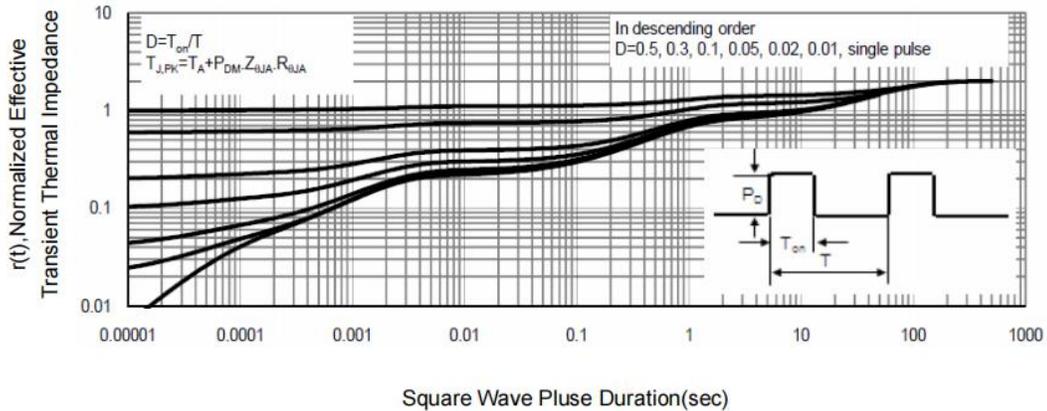
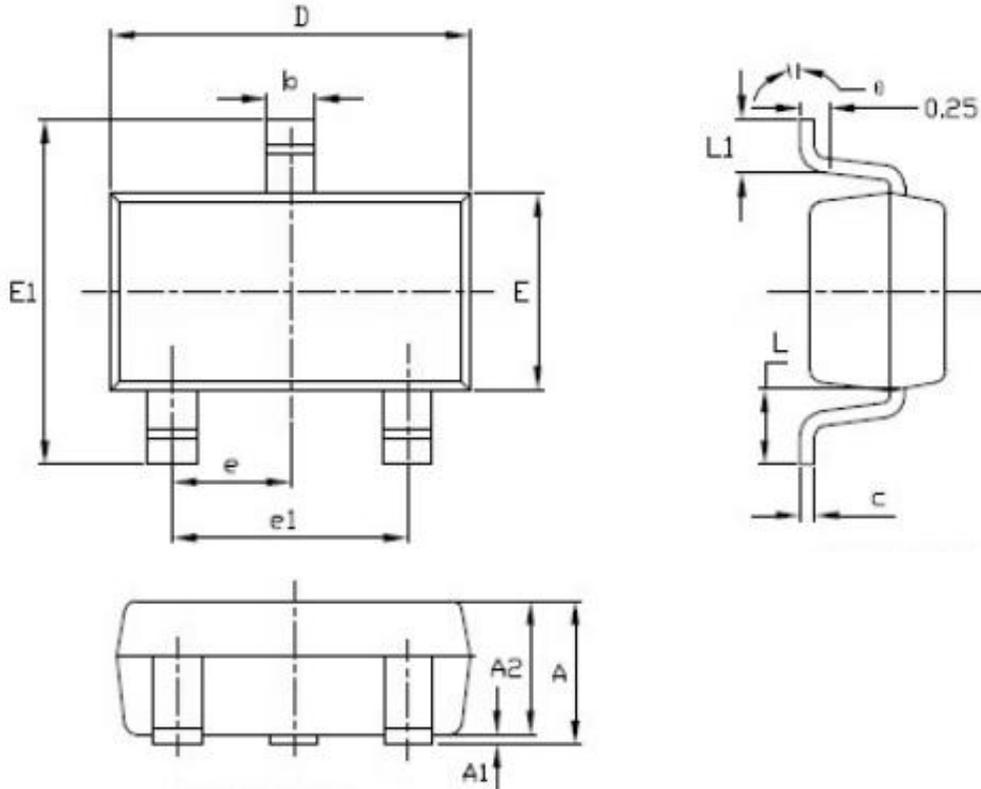


Figure 11: Transient Thermal Response Curve

■ Dimension 外形封装尺寸



| Symbol | Dimensions In Millimeters | | Dimensions In Inches | |
|--------|---------------------------|-------|----------------------|-------|
| | Min | Max | Min | Max |
| A | 1.050 | 1.250 | 0.041 | 0.049 |
| A1 | 0.000 | 0.100 | 0.000 | 0.004 |
| A2 | 1.050 | 1.150 | 0.041 | 0.045 |
| b | 0.300 | 0.500 | 0.012 | 0.020 |
| c | 0.100 | 0.200 | 0.004 | 0.008 |
| D | 2.820 | 3.020 | 0.111 | 0.119 |
| E | 1.500 | 1.700 | 0.059 | 0.067 |
| E1 | 2.650 | 2.950 | 0.104 | 0.116 |
| e | 0.900 | 1.00 | 0.035 | 0.039 |
| e1 | 1.800 | 2.000 | 0.071 | 0.079 |
| L | 0.450 | 0.650 | 0.018 | 0.026 |
| L1 | 0.300 | 0.600 | 0.012 | 0.024 |
| θ | 0° | 8° | 0° | 8° |